NSN 5961-01-014-1601

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-014-1601

Inclosure Material:

Metal

Overall Length:

Between 0.250 inches and 0.450 inches

Overall Diameter:

0.875 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Criticality Code Justification:

Feat

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

100.0 breakdown voltage, collector-to-base, emitter open and 80.0 breakdown voltage, collector-to-emitter, base open and 7.0

breakdown voltage, emitter-to-base, collector open

Current Rating Per Characteristic:

10.00 amperes source cutoff current and 4.00 amperes source cutoff current

Power Rating Per Characteristic:

150.0 watts small-signal input power, common-collector

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

Special Features:

Item must comply with rqmt of desc @production standard no. L01921; junction pattern arrangement: npn

Terminal Type And Quantity:

1 case and 2 pin

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0